

512k x 8 Low Power SRAM 32pin SOP Package

Revision	Details	Date
Rev 1.0	Preliminary datasheet	Mar. 2019

FEATURES

- Fast access time : 70ns
- Low power consumption:
Operating current : 20mA (TYP.)
Standby current : 4 μ A (TYP.)
- Single 2.7V ~ 5.5V power supply
- All outputs TTL compatible
- Fully static operation
- Tri-state output
- Data retention voltage : 1.5V (MIN.)
- **ROHS Compliant-Pb free**
- Package : 32-pin 450 mil SOP
- Operating Temperature
Automotive Grade 1 -40 $^{\circ}$ C ~+125 $^{\circ}$ C

GENERAL DESCRIPTION

The AS6C4008-70SAN is a 4,194,304-bit low power CMOS static random access memory organized as 524,288 words by 8 bits. It is fabricated using very high performance, high reliability CMOS technology. Its standby current is stable within the range of operating temperature.

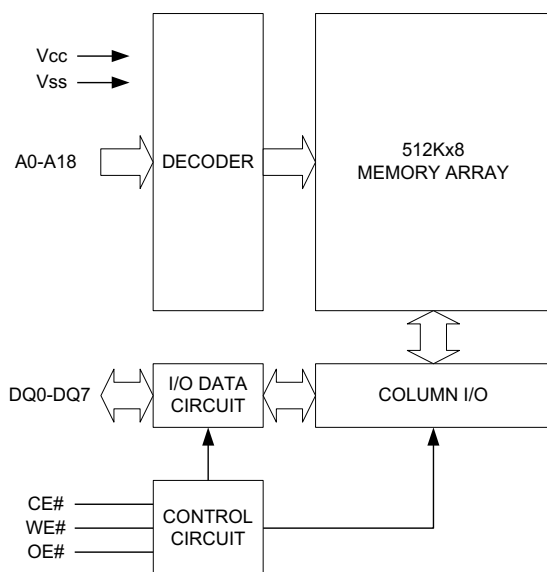
The AS6C4008-70SAN is well designed for very low power system applications, and particularly well suited for battery back-up nonvolatile memory application.

The AS6C4008-70SAN operates from a single power supply of 2.7V ~ 5.5V and all inputs and outputs are fully TTL compatible

PRODUCT FAMILY

Product Family	Operating Temperature	Vcc Range	Speed	Power Dissipation	
				Standby(Isb,TYP.)	Operating(Icc,TYP.)
AS6C4008-70SAN	-40 $^{\circ}$ C ~+125 $^{\circ}$ C	2.7 ~ 5.5V	70ns	4 μ A	20mA

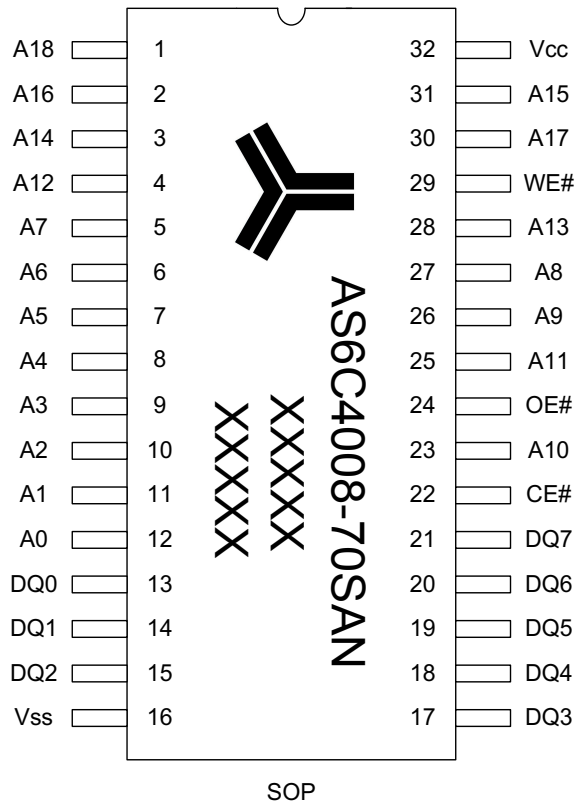
FUNCTIONAL BLOCK DIAGRAM



PIN DESCRIPTION

SYMBOL	DESCRIPTION
A0 - A18	Address Inputs
DQ0 – DQ7	Data Inputs/Outputs
CE#	Chip Enable Inputs
WE#	Write Enable Input
OE#	Output Enable Input
Vcc	Power Supply
Vss	Ground
NC	No Connection

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS*

PARAMETER	SYMBOL	RATING	UNIT
Voltage on V _{CC} relative to V _{SS}	V _{T1}	-0.5 to 6.5	V
Voltage on any other pin relative to V _{SS}	V _{T2}	-0.5 to V _{CC} +0.5	V
Operating Temperature	T _A	-40 to 125(A grade)	°C
Storage Temperature	T _{STG}	-65 to 150	°C
Power Dissipation	P _D	1	W
DC Output Current	I _{OUT}	50	mA

*Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to the absolute maximum rating conditions for extended period may affect device reliability.

TRUTH TABLE

MODE	CE#	OE#	WE#	I/O OPERATION	SUPPLY CURRENT
Standby	H	X	X	High-Z	I _{SB1}
Output Disable	L	H	H	High-Z	I _{CC} , I _{CC1}
Read	L	L	H	D _{OUT}	I _{CC} , I _{CC1}
Write	L	X	L	D _{IN}	I _{CC} , I _{CC1}

Note: H = V_{IH}, L = V_{IL}, X = Don't care.

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP. *4	MAX.	UNIT
Supply Voltage	V _{CC}		2.7	3.0	5.5	V
Input High Voltage	V _{IH} *1	V _{CC} = 4.5V ~ 5.5V	2.4	-	V _{CC} +0.3	V
		V _{CC} = 2.7V ~ 4.5V	2.2	-	V _{CC} +0.3	V
Input Low Voltage	V _{IL} *2	V _{CC} = 4.5V ~ 5.5V	- 0.2	-	0.8	V
		V _{CC} = 2.7V ~ 4.5V	- 0.2	-	0.6	V
Input Leakage Current	I _{LI}	V _{CC} ≥ V _{IN} ≥ V _{SS}	- 2	-	2	μA
Output Leakage Current	I _{LO}	V _{CC} ≥ V _{OUT} ≥ V _{SS} , Output Disabled	- 2	-	2	μA
Output High Voltage	V _{OH}	I _{OH} = -1mA	2.4	2.7	-	V
Output Low Voltage	V _{OL}	I _{OL} = 2mA	-	-	0.4	V
Average Operating Power supply Current	I _{CC}	Cycle time = Min. CE# = V _{IL} I _{I/O} = 0mA Other pins at V _{IL} or V _{IH}	-	20	50	mA
	I _{CC1}	Cycle time = 1μs CE# ≤ 0.2V, I _{I/O} = 0mA Other pins at 0.2V or V _{CC} -0.2V	-	4	10	mA
Standby Power Supply Current	I _{SB1}	CE# ≥ V _{CC} -0.2V Others at 0.2V or V _{CC} - 0.2V	-	4	80	μA

Notes:

- V_{IH}(max) = V_{CC} + 3.0V for pulse width less than 6ns.
- V_{IL}(min) = V_{SS} - 3.0V for pulse width less than 6ns.
- Over/Undershoot specifications are characterized, not 100% tested.
- Typical values are included for reference only and are not guaranteed or tested.
Typical values are measured at V_{CC} = V_{CC}(TYP.) and T_A = 25°C
- This parameter is measured at V_{CC} = 3.0V

CAPACITANCE (T_A = 25°C, f = 1.0MHz)

PARAMETER	SYMBOL	MIN.	MAX	UNIT
Input Capacitance	C _{IN}	-	6	pF
Input/Output Capacitance	C _{I/O}	-	8	pF

Note : These parameters are guaranteed by device characterization, but not production tested.

AC TEST CONDITIONS

Input Pulse Levels	0.2V to V _{CC} - 0.2V
Input Rise and Fall Times	3ns
Input and Output Timing Reference Levels	1.5V
Output Load	C _L = 30pF + 1TTL, I _{OH} /I _{OL} = -2mA/4mA

AC ELECTRICAL CHARACTERISTICS

(1) READ CYCLE

PARAMETER	SYM.	AS6C4008-70SAN		UNIT
		MIN.	MAX.	
Read Cycle Time	t _{RC}	70	-	ns
Address Access Time	t _{AA}	-	70	ns
Chip Enable Access Time	t _{ACE}	-	70	ns
Output Enable Access Time	t _{OE}	-	35	ns
Chip Enable to Output in Low-Z	t _{CLZ} *	10	-	ns
Output Enable to Output in Low-Z	t _{OLZ} *	5	-	ns
Chip Disable to Output in High-Z	t _{CHZ} *	-	25	ns
Output Disable to Output in High-Z	t _{OHZ} *	-	25	ns
Output Hold from Address Change	t _{OH}	10	-	ns

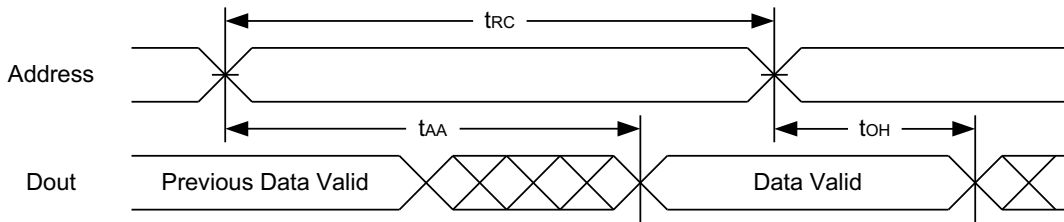
(2) WRITE CYCLE

PARAMETER	SYM.	AS6C4008-70SAN		UNIT
		MIN.	MAX.	
Write Cycle Time	t _{WC}	70	-	ns
Address Valid to End of Write	t _{AW}	60	-	ns
Chip Enable to End of Write	t _{CW}	60	-	ns
Address Set-up Time	t _{AS}	0	-	ns
Write Pulse Width	t _{WP}	55	-	ns
Write Recovery Time	t _{WR}	0	-	ns
Data to Write Time Overlap	t _{DW}	30	-	ns
Data Hold from End of Write Time	t _{DH}	0	-	ns
Output Active from End of Write	t _{OW} *	5	-	ns
Write to Output in High-Z	t _{WHZ} *	-	25	ns

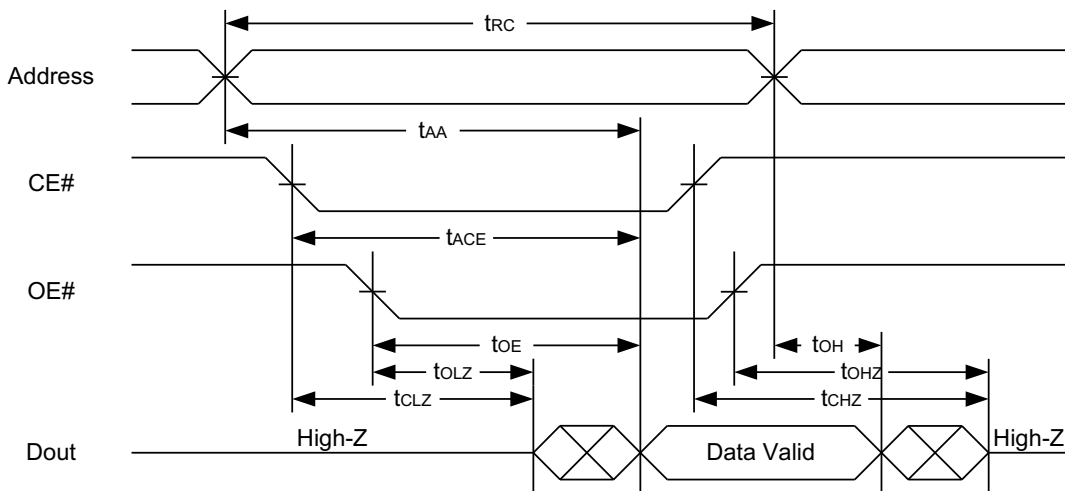
*These parameters are guaranteed by device characterization, but not production tested.

TIMING WAVEFORMS

READ CYCLE 1 (Address Controlled) (1,2)



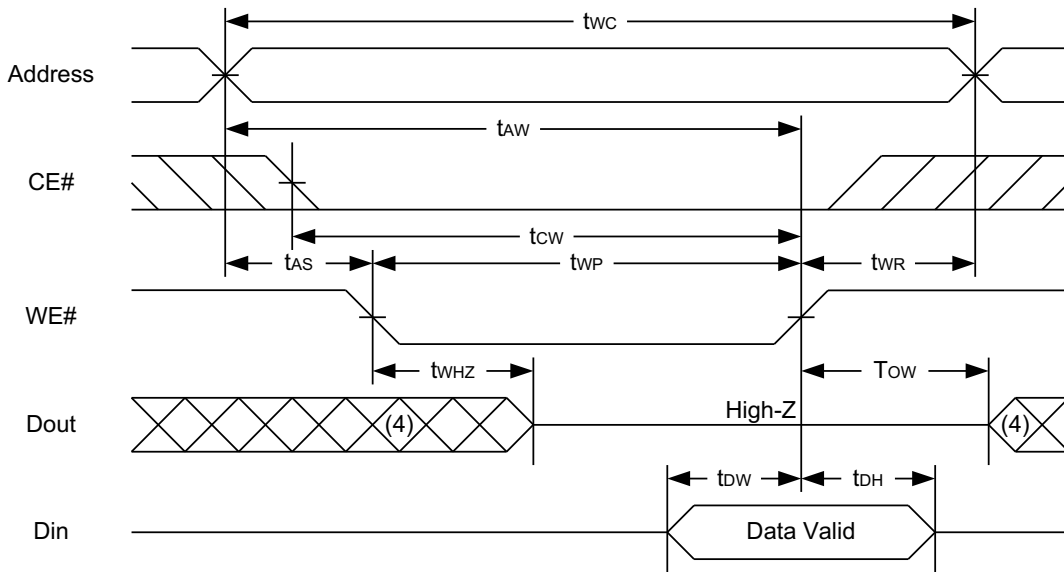
READ CYCLE 2 (CE# and OE# Controlled) (1,3,4,5)



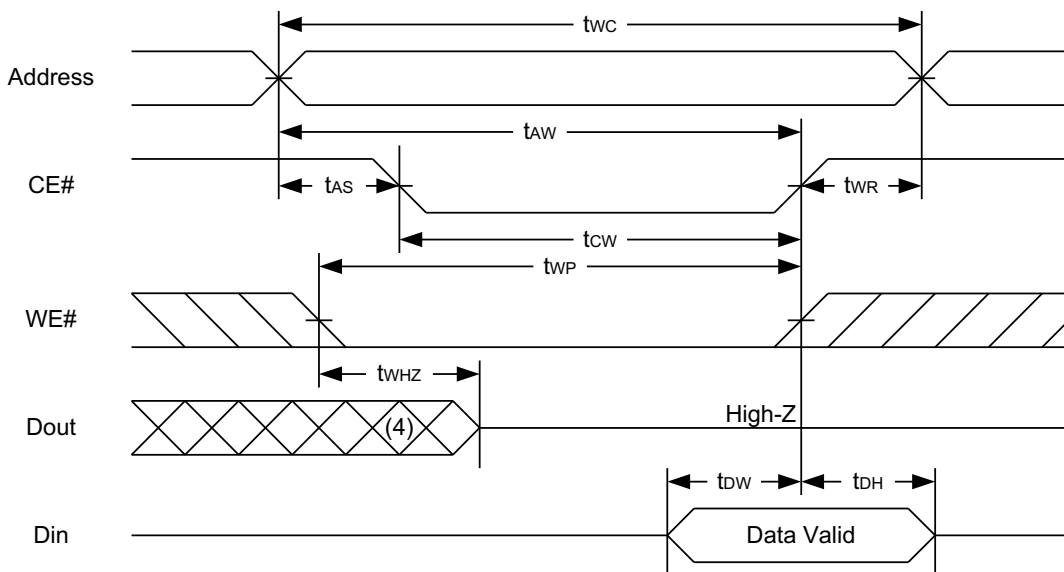
Notes :

1. WE# is high for read cycle.
2. Device is continuously selected OE# = low, CE# = low.
3. Address must be valid prior to or coincident with CE# = low.; otherwise t_{AA} is the limiting parameter.
4. t_{CLZ} , t_{OLZ} , t_{CHZ} and t_{OHZ} are specified with $C_L = 5\text{pF}$. Transition is measured $\pm 500\text{mV}$ from steady state.
5. At any given temperature and voltage condition, t_{CHZ} is less than t_{CLZ} , t_{OHZ} is less than t_{OLZ} .

WRITE CYCLE 1 (WE# Controlled) (1,2,3,5,6)



WRITE CYCLE 2 (CE# Controlled) (1,2,5,6)



Notes :

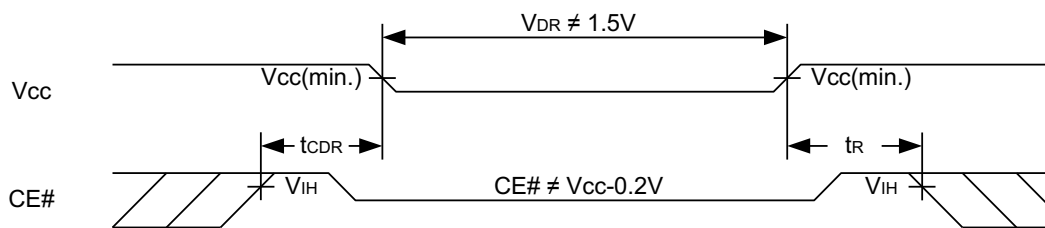
1. WE#, CE# must be high during all address transitions.
2. A write occurs during the overlap of a low CE#, low WE#.
3. During a WE# controlled write cycle with OE# low, t_{tw} must be greater than t_{whz} + t_{tdw} to allow the drivers to turn off and data to be placed on the bus.
4. During this period, I/O pins are in the output state, and input signals must not be applied.
5. If the CE# low transition occurs simultaneously with or after WE# low transition, the outputs remain in a high impedance state.
6. t_{tdw} and t_{whz} are specified with C_L = 5pF. Transition is measured ±500mV from steady state.

DATA RETENTION CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
V _{CC} for Data Retention	V _{DR}	CE# ≥ V _{CC} - 0.2V	1.5	-	5.5	V
Data Retention Current	I _{DR}	V _{CC} = 1.5V CE# ≥ V _{CC} - 0.2V Other pins at 0.2V or V _{CC} -0.2V	-	2	80	μA
Chip Disable to Data Retention Time	t _{CDR}	See Data Retention Waveforms (below)	0	-	-	ns
Recovery Time	t _R		t _{RC} *	-	-	ns

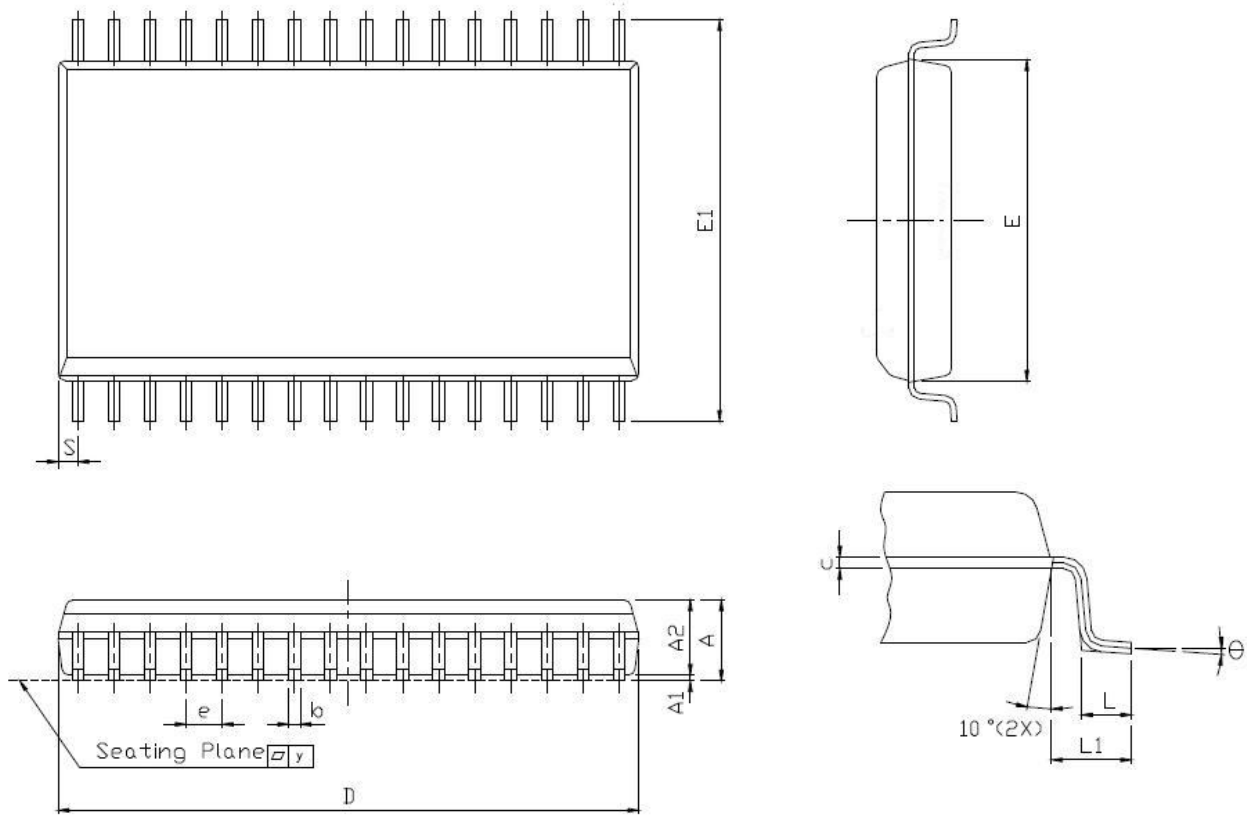
t_{RC}* = Read Cycle Time

DATA RETENTION WAVEFORM



PACKAGE OUTLINE DIMENSION

32 pin 450 mil SOP Package Outline Dimension



SYM.	UNIT	INCH.(BASE)	MM(REF)
A		0.120(MAX)	3.048(MAX)
A1		0.004(MIN)	0.102(MIN)
A2		0.116(MAX)	2.946(MAX)
b		0.016(TYP)	0.406(TYP)
c		0.008(TYP)	0.203(TYP)
D		0.817(MAX)	20.75(MAX)
E		0.445±0.006	11.303±0.152
E1		0.555±0.025	14.097±0.635
e		0.050(TYP)	1.270(TYP)
L		0.033±0.017	0.838±0.432
L1		0.055±0.008	1.397±0.203
S		0.026(MAX)	0.660(MAX)
y		0.004(MAX)	0.101(MAX)
Θ		0° -10°	0° -10°

ORDERING INFORMATION

Package Type	Access Time (Speed)(ns)	Temperature Range(°C)	Packing Type	Alliance Memory Part Number
32 Pin(450mil) SOP	70	-40°C~125°C	Tube	AS6C4008-70SAN
			Tape Reel	AS6C4008-70SANTR

PART NUMBERING SYSTEM

AS6C	4008	-70	S	A	N
Low power SRAM prefix	Device Number 40 = 4M 08 = by 8	Access Time	Package Options: S = 32 pin 450 mil SOP	Temperature Range: A= Automotive (-40°C to +125°C)	N = Lead Free ROHS Compliant Part



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